
Single BiCMOS rail-to-rail micropower comparator

Features

- Rail-to-rail inputs
- Open drain output
- Supply operation from 2.7V to 10V
- Typical supply current: 6 μ A @ 5V
- Response time of 0.5 μ s at 5V
- Low input current
- ESD protection: 2kV (HBM), 200V (MM)
- Available in tiny SOT23-5 package

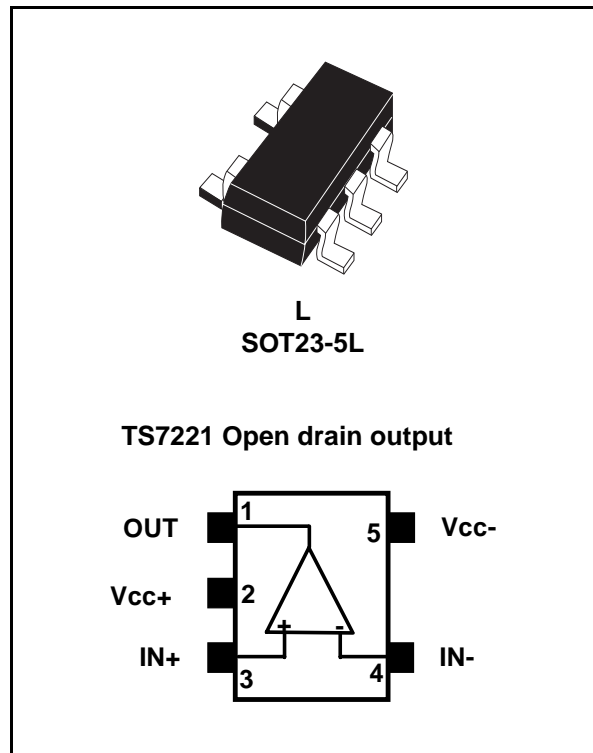
Applications

- Battery-powered systems
- Notebooks and PDAs
- PCMCIA cards
- Cellulare and mobile communication
- Alarm and security systems
- Replacement of amplifiers used in comparator configuration for better performance

Description

The TS7221 is a micropower comparator featuring rail-to-rail input performance in a tiny SOT23-5 package. This comparator is ideally suited to space and weight-critical applications. It is fully specified at 2.7V, 5V and 10V operation over the industrial temperature range (-40°C to +85°C).

The TS7221 features an open drain output stage. The speed-to-power ratio makes this device ultra-versatile for a wide range of applications.



1 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
ESD	Human body model (HBM)	2000	V
	Machine model (MM)	200	
V _{ID}	Differential input voltage	(V _{CC} ⁻) -0.3 to (V _{CC} ⁺) +0.3	V
V _{IN}	Input voltage ⁽¹⁾	(V _{CC} ⁻) -0.3 to (V _{CC} ⁺) +0.3	V
V _{OUT}	Output voltage	12	V
V _{CC}	Supply voltage	12	V
I _{IN}	Current at input pins ⁽¹⁾	± 5	mA
I _{OUT}	Current at output pin	± 30	mA
T _{Lead}	Lead temperature (soldering 10 seconds, Pb-free package)	260	°C
T _{stg}	Storage temperature	-65 to +150	°C
T _J	Junction temperature	150	°C
P _D	Power dissipation ⁽²⁾ SOT23-5	500	mW

1. The magnitude of input voltages must never exceed 0.3V beyond the supply voltage.
2. T_J = 150°C, T_{AMB} = 25°C with R_{TH-JA} = 250°C/W for SOT23-5 package.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	2.7 to 10	V
T _{amb}	Ambient temperature	-40 to +85	°C
V _{icm}	Common mode input voltage range	(V _{CC} ⁻) -0.3 to (V _{CC} ⁺) +0.3	V

2 Electrical characteristics

Table 3. Electrical characteristics at $V_{CC}^+ = 2.7V$, $T_{amb} = 25^\circ C$ (unless otherwise specified)⁽¹⁾

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{IO}	Input offset voltage (full common mode range) – TS7221A at $T_{min} \leq T_{amb} \leq T_{max}$ – TS7221B at $T_{min} \leq T_{amb} \leq T_{max}$			7 10 15 18	mV
ΔV_{IO}	Input offset voltage drift with temperature		6		$\mu V/^\circ C$
I_{IB}	Input bias current ⁽²⁾ at $T_{min} \leq T_{amb} \leq T_{max}$		1	300 600	pA
I_{IO}	Input offset current ⁽²⁾ at $T_{min} \leq T_{amb} \leq T_{max}$		1	150 300	pA
CMRR	Common-mode rejection ratio ($0 < V_{icm} < 2.7V$)		65		dB
PSRR	Power supply rejection ratio ($2.7 < V_{CC} < 10V$)		80		dB
A_{VD}	Voltage gain ⁽³⁾		240		dB
V_{icm}	Input common mode voltage range at $T_{min} \leq T_{amb} \leq T_{max}$	-0.3 0.0		3 2.7	V
I_{OH}	High level output voltage ($I_N^+ = 0.5V$, $I_N^- = 0V$ & $OUT = 10V$)		0.1	500	nA
V_{OL}	Low level output voltage, $I_{sink} = 5mA$ at $T_{min} \leq T_{amb} \leq T_{max}$		0.2	0.35 0.45	V
I_{CC}	Supply current Output low Output high		6 8	12 14	μA
T_{PLH}	Response time low to high ($V_{ic} = 1.35V$, $C_L = 50pF$, $R_L = 10k\Omega$) Overdrive = 10mV Overdrive = 100mV		1.5 0.6		μs
T_{PHL}	Response time high to low ($V_{ic} = 1.35V$, $C_L = 50pF$, $R_L = 10k\Omega$) Overdrive = 10mV Overdrive = 100mV		1.5 0.5		μs
T_F	Fall time $C_L = 50pF$, $R_L = 5k\Omega$, Overdrive = 10mV		0.3		μs
T_R	Rise time $C_L = 50pF$, $R_L = 5k\Omega$, Overdrive = 10mV		0.3		μs

1. Limits are 100% production tested at $+25^\circ C$. Behavior at the temperature range limits is guaranteed through correlation and by design.
2. Maximum values include unavoidable inaccuracies of industrial testing.
3. Design evaluation.

Table 4. Electrical characteristics for $V_{CC}^+ = 5V$, $T_{amb} = 25^\circ C$ (unless otherwise specified)⁽¹⁾

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{IO}	Input offset voltage (full common mode range) – TS7221A at $T_{min} \leq T_{amb} \leq T_{max}$ – TS7221B $T_{min} \leq T_{amb} \leq T_{max}$			7 10 15 18	mV
ΔV_{IO}	Input offset voltage drift with temperature		6		$\mu V/^\circ C$
I_{IB}	Input bias current ⁽²⁾ at $T_{min} \leq T_{amb} \leq T_{max}$		1	300 600	pA
I_{IO}	Input offset current ⁽²⁾ at $T_{min} \leq T_{amb} \leq T_{max}$		1	150 300	pA
CMRR	Common-mode rejection ratio ($0 < V_{icm} < 5V$)		70		dB
PSRR	Power supply rejection ratio ($2.7 < V_{CC} < 10V$)		80		dB
A_{VD}	Voltage gain ⁽³⁾		240		dB
V_{icm}	Input common mode voltage range at $T_{min} \leq T_{amb} \leq T_{max}$	-0.3 0.0		5.3 5.0	V
I_{OH}	High level output voltage ($I_N^+ = 0.5V$, $I_N^- = 0V$ & $OUT = 10V$)		0.1	500	nA
V_{OL}	Low level output voltage, $I_{sink} = 5mA$ at $25^\circ C$ at $T_{min} \leq T_{amb} \leq T_{max}$		0.2	0.40 0.55	V
I_{CC}	Supply current Output low Output high		6 8	12 14	μA
T_{PLH}	Response time low to high ($V_{ic} = 2.5V$, $C_L = 50pF$, $R_L = 10k\Omega$) Overdrive = 10mV Overdrive = 100mV		2 0.5		μs
T_{PHL}	Response time high to low ($V_{ic} = 2.5V$, $C_L = 50pF$, $R_L = 10k\Omega$) Overdrive = 10mV Overdrive = 100mV		2 0.4		μs
T_F	Fall time $C_L = 50pF$, $R_L = 5k\Omega$, Overdrive = 10mV		0.3		μs
T_R	Rise time $C_L = 50pF$, $R_L = 5k\Omega$, Overdrive = 10mV		0.3		μs

1. Limits are 100% production tested at $+25^\circ C$. Behavior at the temperature range limits is guaranteed through correlation and by design.
2. Maximum values include unavoidable inaccuracies of industrial testing.
3. Design evaluation.

Table 5. Electrical characteristics for $V_{CC^+} = 10V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)⁽¹⁾

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{IO}	Input offset voltage (full common mode range) – TS7221A at $T_{min} \leq T_{amb} \leq T_{max}$ – TS7221B $T_{min} \leq T_{amb} \leq T_{max}$			7 10 15 18	mV
ΔV_{IO}	Input offset voltage drift with temperature		6		$\mu V/^{\circ}C$
I_{IB}	Input bias current ⁽²⁾ at $T_{min} \leq T_{amb} \leq T_{max}$		1	300 600	pA
I_{IO}	Input offset current ⁽²⁾ at $T_{min} \leq T_{amb} \leq T_{max}$		1	150 300	pA
CMRR	Common-mode rejection ratio ($0 < V_{icm} < 10V$)		75		dB
PSRR	Power supply rejection ratio ($2.7 < V_{CC} < 10V$)		80		dB
A_{VD}	Voltage gain ⁽³⁾		240		dB
V_{ICM}	Input common mode voltage range at $T_{min} \leq T_{amb} \leq T_{max}$	-0.3 0.0		10.3 10.0	V
I_{OH}	High level output voltage ($I_{N^+}=0.5V$, $I_{N^-}=0V$ & $OUT=10V$)		0.1	500	nA
V_{OL}	Low level output voltage, $I_{sink} = 5mA$ at $T_{min} \leq T_{amb} \leq T_{max}$		0.2	0.40 0.55	V
I_{CC}	Supply current Output low Output high		7 10	14 16	μA
T_{PLH}	Response time low to high ($V_{ic} = 5V$, $C_L = 50pF$, $R_L=10k\Omega$) Overdrive = 10mV Overdrive = 100mV		3 0.5		μs
T_{PHL}	Response time high to low ($V_{ic} = 5V$, $C_L = 50pF$, $R_L=10k\Omega$) Overdrive = 10mV Overdrive = 100mV		4 0.4		μs
T_F	Fall time $C_L = 50pF$, $R_L=5k\Omega$, Overdrive = 10mV		0.3		μs
T_R	Rise time $C_L = 50pF$, $R_L=5k\Omega$, Overdrive = 10mV		0.3		μs

1. Limits are 100% production tested at $+25^{\circ}C$. Behavior at the temperature range limits is guaranteed through correlation and by design.
2. Maximum values include unavoidable inaccuracies of industrial testing.
3. Design evaluation.

Figure 1. Supply current vs. supply voltage (output low)

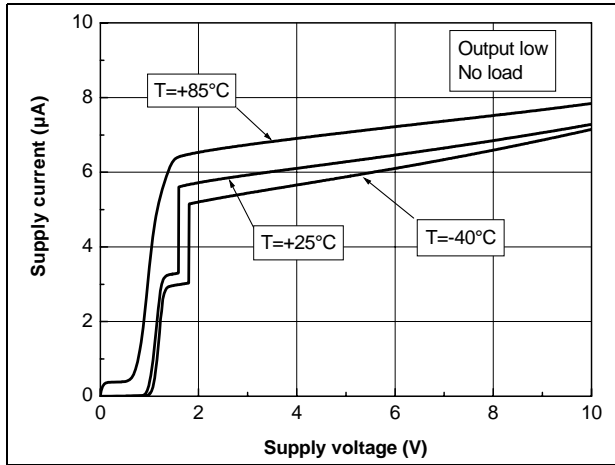


Figure 2. Supply current vs. supply voltage (output high)

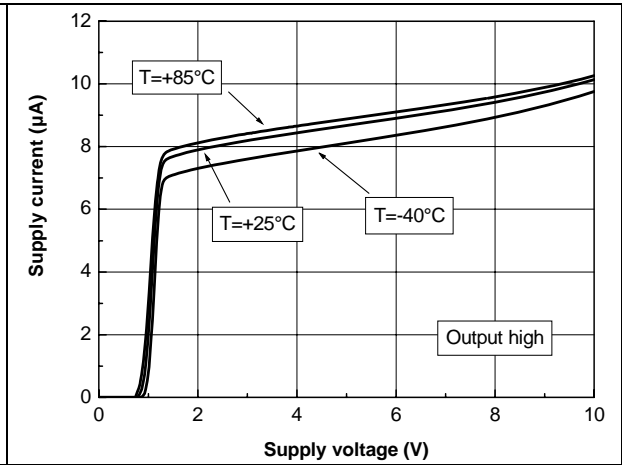


Figure 3. Output sinking current vs. output voltage at $V_{CC} = +2.7V$, $V_{CC} = +5V$

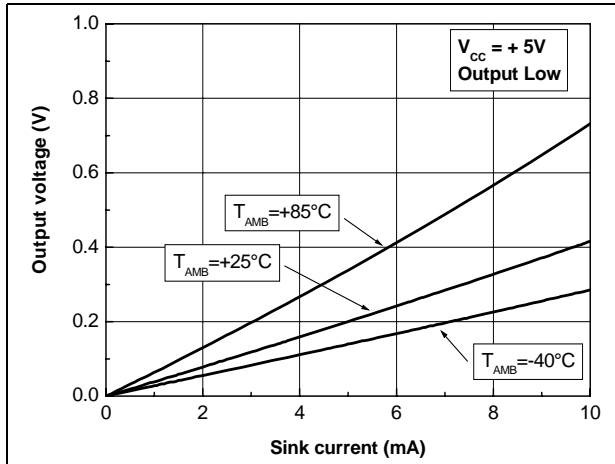


Figure 4. V_{IO} vs. V_{icm} and temperature at $V_{CC} = 2.7V$

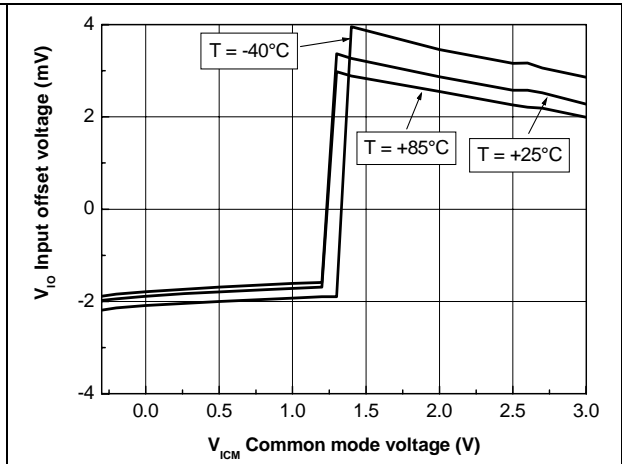


Figure 5. V_{IO} vs. V_{icm} and temperature at $V_{CC} = 5V$

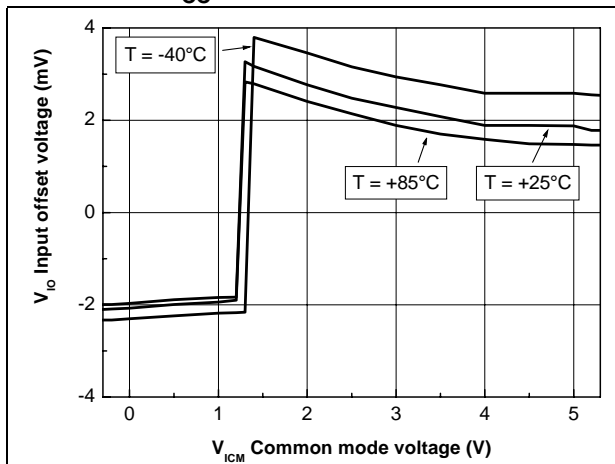


Figure 6. V_{IO} vs. V_{icm} and temperature at $V_{CC} = 10V$

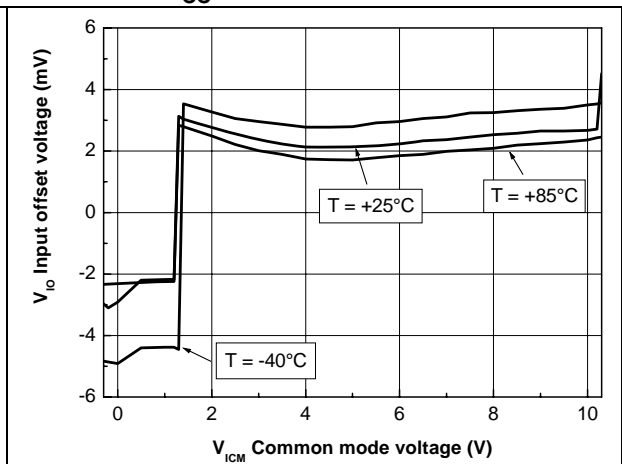


Figure 7. T_{PLH} vs V_{icm} at $V_{CC} = 10V$ and 10mV overdrive

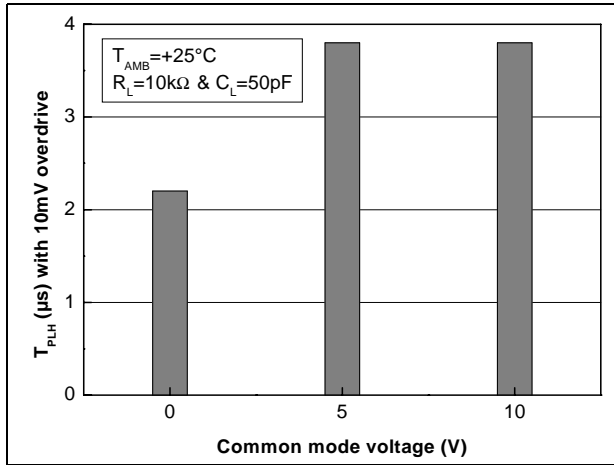


Figure 8. T_{PLH} vs V_{icm} at $V_{CC} = 10V$ and 100mV overdrive

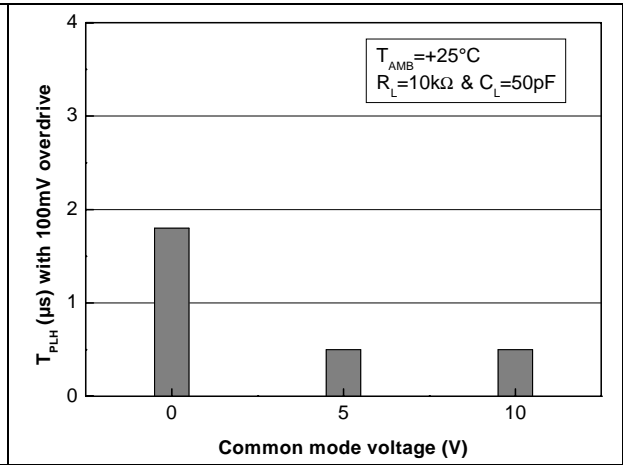


Figure 9. T_{PLH} vs V_{icm} at $V_{CC} = 5V$ and 10mV overdrive

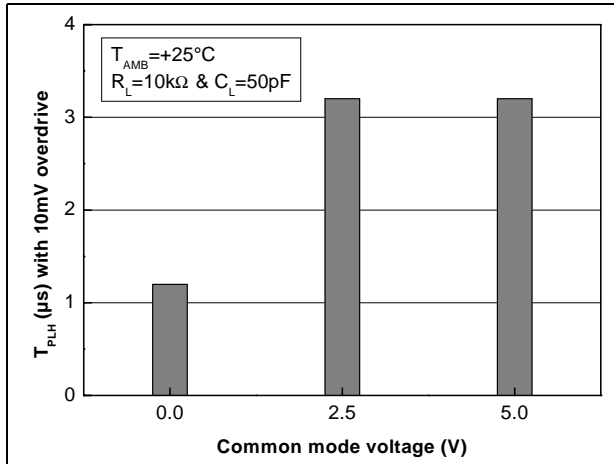


Figure 10. T_{PLH} vs V_{icm} at $V_{CC} = 5V$ and 100mV overdrive

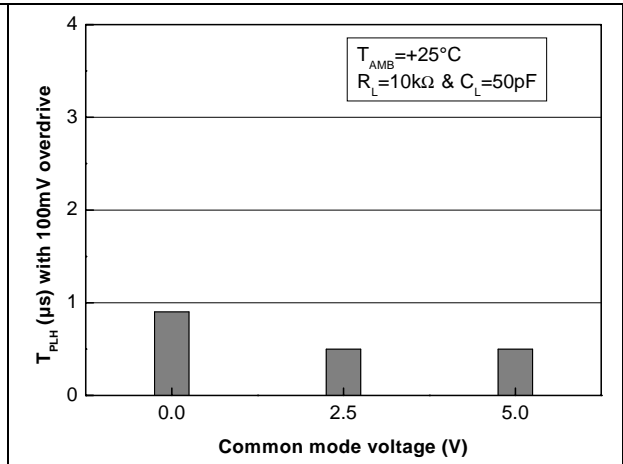


Figure 11. T_{PHL} vs V_{icm} at $V_{CC} = 10V$ and 10mV overdrive

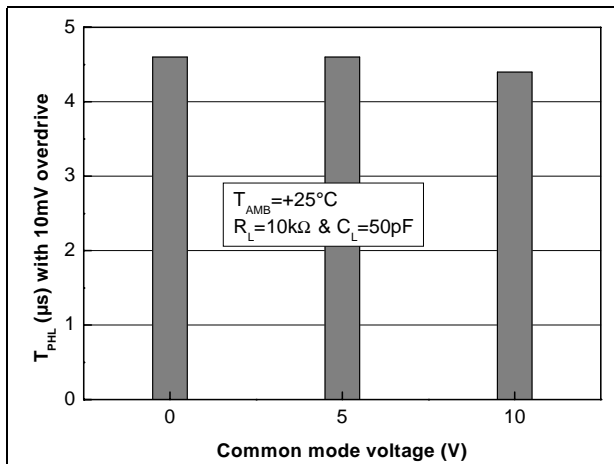


Figure 12. T_{PHL} vs V_{icm} at $V_{CC} = 10V$ and 100mV overdrive

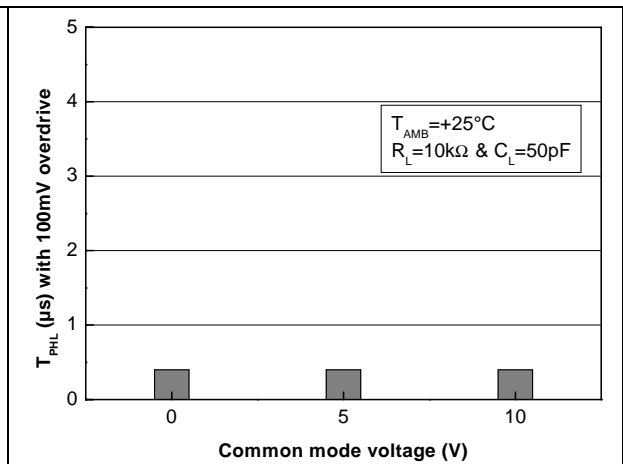


Figure 13. T_{PHL} vs V_{icm} at $V_{CC}=5V$ and 10mV overdrive

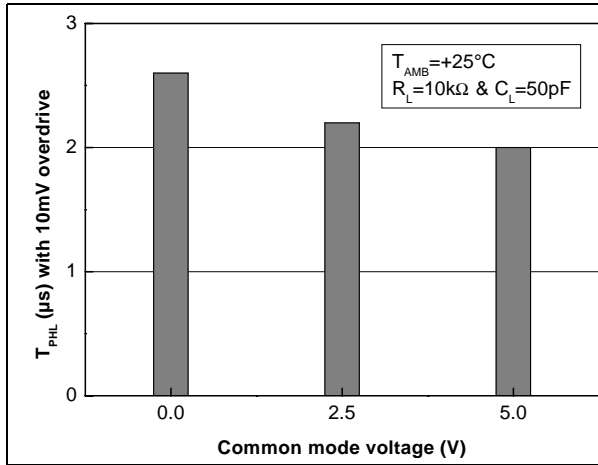
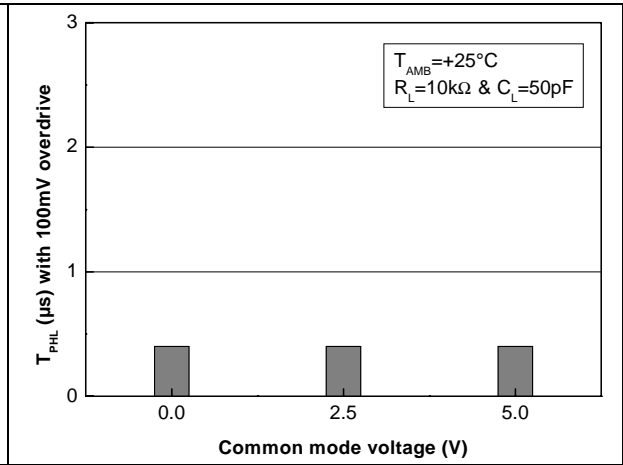


Figure 14. T_{PHL} vs V_{icm} at $V_{CC}=5V$ and 100mV overdrive



3 Package information

In order to meet environmental requirements, STMicroelectronics offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an STMicroelectronics trademark. ECOPACK specifications are available at: www.st.com.

Figure 15. SOT23-5L package mechanical data

Ref.	Dimensions					
	Millimeters			Mils		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90		1.45	35.4		57.1
A1	0.00		0.15	0.00		5.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
C	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	2.60		3.00	102.3		118.1
E1	1.50		1.75	59.0		68.8
e		0.95			37.4	
e1		1.9			74.8	
L	0.35		0.55	13.7		21.6

The diagram shows two views of the SOT23-5L package. The left view is a side profile showing dimensions A (total width), A1 (width of the main body), A2 (width of the lead), C (lead thickness), and L (lead length). The right view is a top-down view showing dimensions D (total length), E (total height), E1 (height of the main body), e (lead pitch), e1 (total lead pitch), and b (lead width).

4 Ordering information

Table 6. Order codes

Part number	Temperature range	Package	Packing	Marking
TS7221AILT	-40°C, +85°C	SOT23-5L	Tape & reel	K518
TS7221BILT				K519
TS7221AIYLT ⁽¹⁾		SOT23-5L (automotive grade)		K522
TS7221BIYLT ⁽¹⁾				K523

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

5 Revision history

Table 7. Document revision history

Date	Revision	Changes
1-Dec-2002	1	Initial release
1-Sep-2005	2	Update of datasheet presentation and format. Change of T_{lead} temperature in Table 1 on page 2 , to reflect change to Pb-free package. Corrections to V_{icm} upper rail parameters in Electrical characteristics tables. Addition of Pb-free information in Section 3: Package information on page 9 . Correction to package mechanical data given in Figure 15 on page 9 .
26-Mar-2007	3	Added automotive grade part numbers in Section 4: Ordering information on page 10 .
5-Jul-2007	4	Corrected automotive grade part numbers in Table 6: Order codes .

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